

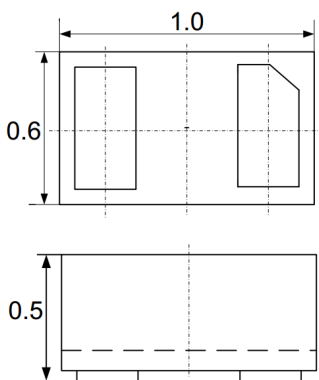
## Description

The DC0521P1L is a bi-directional TVS diode, utilizing leading monolithic silicon technology to provide fast re-sponse time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive data and power line. The DC0521P1L complies with the IEC 61000-4-2 (ESD) with  $\pm 30$  kV air and  $\pm 30$  kV contact discharge. It is assembled into an ultra-small 1.0x0.6x0.5mm lead-free DFN package. The small size and high ESD surge protection make DC0521P1L an ideal choice to protect cell phone, digital cameras, audio players and many other portable applications.

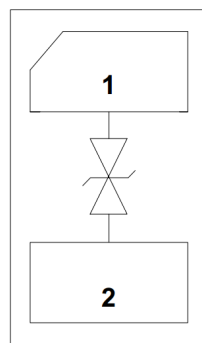
## Mechanical Characteristics

- ◆ Package: DFN1006-2 (1.0 x0.6 x0.5mm)
- ◆ Case Material: "Green" Molding Compound.
- ◆ Moisture Sensitivity: Level 3 per J-STD-020
- ◆ Terminal Connections: See Diagram Below
- ◆ Marking Information: See Below

## Dimensions and Pin Configuration



Package Dimensions



Circuit and Pin Schematic

## Features

- ◆ Ultra small package: 1.0x0.6x0.5mm
- ◆ Protects one data or power line
- ◆ Ultra low leakage: nA level
- ◆ Low operating voltage: 5V
- ◆ Low clamping voltage
- ◆ 2-pin leadless package
- ◆ Complies with following standards:
  - IEC 61000-4-2 (ESD) immunity test
    - Air discharge:  $\pm 30$  kV
    - Contact discharge:  $\pm 30$  kV
  - IEC61000-4-5 (Lightning) 5.5A (8/20 $\mu$ s)
- ◆ RoHS Compliant

## Applications

- ◆ Cellular Handsets and Accessories
- ◆ Personal Digital Assistants
- ◆ Notebooks and Handhelds
- ◆ Portable Instrumentation
- ◆ Digital Cameras
- ◆ Peripherals
- ◆ Audio Players
- ◆ Keypads, Side Keys, LCD Displays

## Marking Information



PB = Device Marking Code

## Ordering Information

Part Number	Marking	Packaging	Reel Size
DC0521P1L	PB	10000/Tape & Reel	7 inch

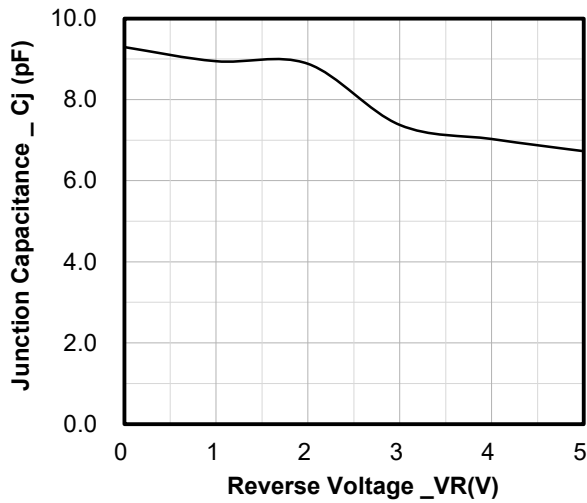
### **Absolute Maximum Ratings ( $T_A=25^\circ\text{C}$ unless otherwise specified)**

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20 $\mu\text{s}$ )	Ppk	60	W
Peak Pulse Current (8/20 $\mu\text{s}$ )	I <sub>PP</sub>	5.5	A
ESD per IEC 61000-4-2 (Air)	V <sub>ESD</sub>	$\pm 20$	kV
ESD per IEC 61000-4-2 (Contact)		$\pm 20$	
Operating Temperature Range	T <sub>J</sub>	-55 to +125	$^\circ\text{C}$
Storage Temperature Range	T <sub>stg</sub>	-55 to +150	$^\circ\text{C}$

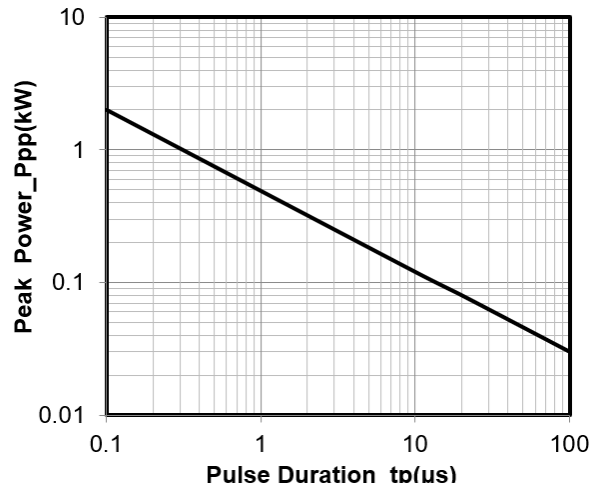
### **Electrical Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise specified)**

Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	V <sub>RWM</sub>			5	V	
Breakdown Voltage	V <sub>BR</sub>	5.6		8	V	I <sub>T</sub> = 1mA
Reverse Leakage Current	I <sub>R</sub>			0.2	$\mu\text{A}$	V <sub>RWM</sub> = 5V
Clamping Voltage	V <sub>C</sub>			8.5	V	I <sub>PP</sub> = 1A
Clamping Voltage	V <sub>C</sub>		9.5	12	V	I <sub>PP</sub> = 5.5A
Junction Capacitance	C <sub>J</sub>		10	15	pF	V <sub>R</sub> = 0V, f = 1MHz

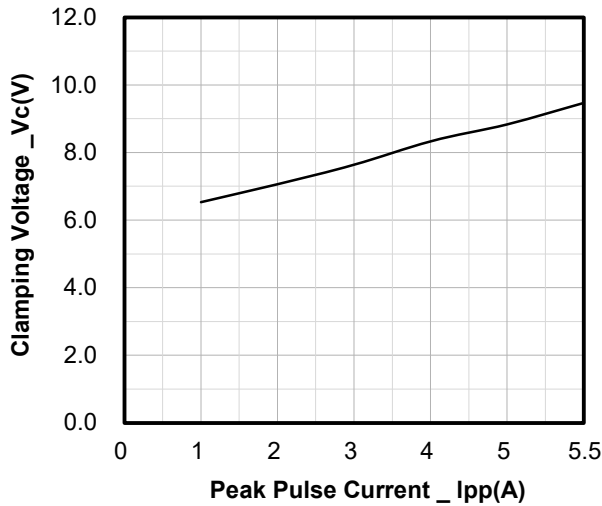
**Typical Performance Characteristics (TA=25°C unless otherwise Specified)**



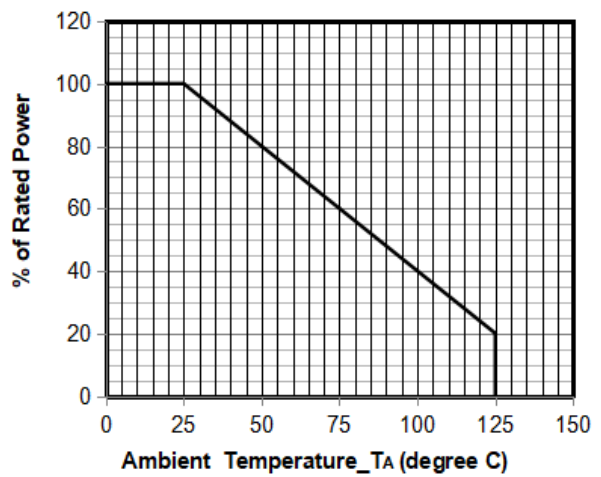
Junction Capacitance vs. Reverse Voltage



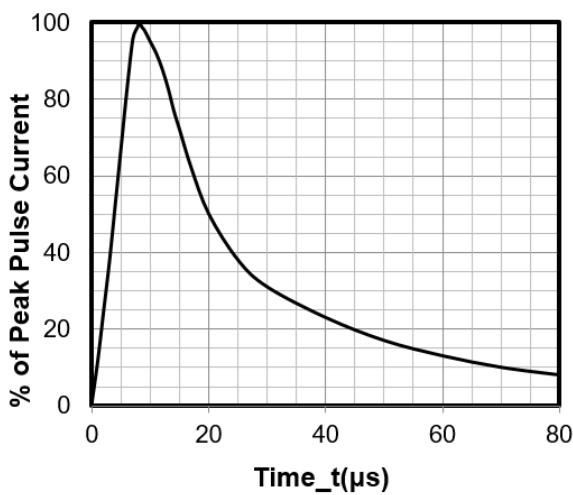
Peak Pulse Power vs. Pulse Time



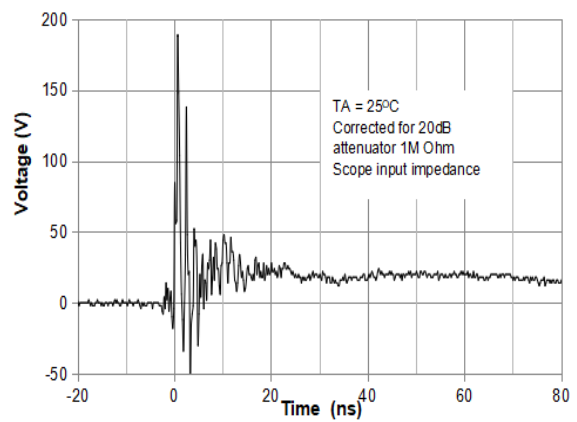
Clamping Voltage vs. Peak Pulse Current (tp = 8/20μs)



Power Derating Curve

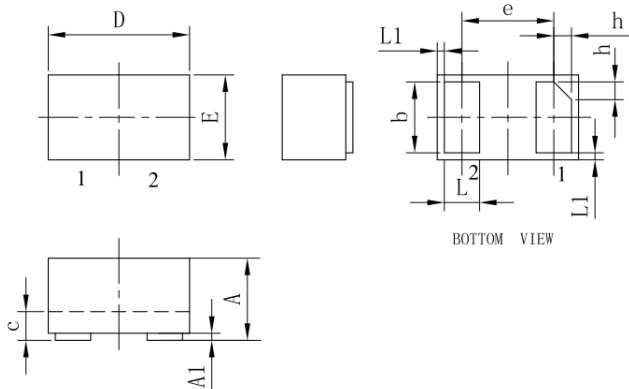


8 X 20μs Pulse Waveform



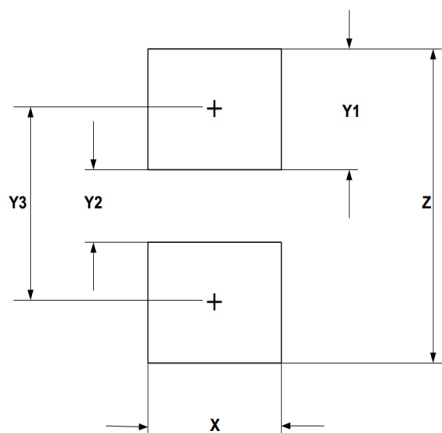
ESD Clamping Voltage  
8 kV Contact per IEC61000-4-2

## DFN1006-2 Package Outline Drawing



SYM	DIMENSIONS					
	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.450	0.500	0.550	0.018	0.020	0.022
A1	0.000	0.020	0.050	0.000	0.001	0.002
b	0.450	0.50	0.550	0.018	0.020	0.022
c	0.120	0.150	0.180	0.005	0.006	0.007
D	0.950	1.000	1.050	0.037	0.039	0.041
e	0.65 BSC			0.026 BSC		
E	0.55	0.60	0.65	0.022	0.024	0.026
L	0.20	0.25	0.30	0.008	0.010	0.012
L1	0.05REF			0.002REF		
h	0.07	0.12	0.17	0.003	0.005	0.007

## Suggested Land Pattern



SYM	DIMENSIONS	
	MILLIMETERS	INCHES
X	0.60	0.024
Y1	0.50	0.020
Y2	0.30	0.012
Y3	0.80	0.032
Z	1.30	0.052

## Contact Information

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